NSN 5962-01-455-6521

Memory Microcircuit - Page 1 of 1



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End Application:
Fy95arc e/i fscm 98897
Features Provided:
Electrostatic sensitive
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Current Rating Per Characteristic:
190.00 milliamperes bias over operating temp and 10.00 milliamperes stand-by
Terminal Surface Treatment:
Solder
Time Rating Per Chacteristic:
20.00 nanoseconds input to output access
Memory Device Type:
Ram
Terminal Type And Quantity:
36 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0